

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L4	5	("20020190269" "5603779" "5882987" "6140210" "6150239").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/12/27 15:49
L5	0	("6833195").URPN.	USPAT	OR	OFF	2005/12/27 15:49
L6	4481	((438/149) or (438/311) or (438/455) or (438/479) or (438/933) or (438/964) or (438/967)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/27 16:12
L7	101	6 and ("GOI" or "GeSOI" or (germanium near2 insulat\$3) or (germanium near2 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:27
L8	14057	("GOI" or "GeSOI" or (germanium near2 insulat\$3) or (germanium near2 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:33
L9	1239	8 and (("Ge" or germanium) near5 (insulat\$3 or dielectric))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:34
L10	429	9 and (epitaxial\$2 near5 ("Ge" or germanium))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:34
L11	305	10 and bond\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:34
L12	15229	("GOI" or "GeOI" or (germanium near2 insulat\$3) or (germanium near2 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:33

L13	104	6 and 12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:33
L14	3	13 not 7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:33
L15	1243	12 and ("Ge" or germanium) near5 (insulat\$3 or dielectric))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:34
L16	429	15 and (epitaxial\$2 near5 ("Ge" or germanium))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:34
L17	305	16 and bond\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:34
L18	0	("2005/0067377"):URPN.	USPAT	OR	OFF	2005/12/27 16:36
S1	2	((("5603779") or ("5882987"))).PN.	USPAT	OR	OFF	2005/03/23 18:53
S2	3933	((438/149) or (438/311) or (438/455) or (438/479) or (438/933) or (438/964) or (438/967)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/22 11:25
S3	3583	S2 and ("GOI" or (germanium adj on adj insulat\$3) naer substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 19:06
S4	8	S2 and ("GOI" or (germanium adj on adj insulat\$3) near substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 19:11

S5	8	S4 and ((dielectric or insulat\$3) near (layer\$1 or film\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 19:11
S6	5	("20020190269" "5603779" "5882987" "6140210" "6150239").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/23 19:09
S7	0	("6833195").URPN.	USPAT	OR	OFF	2005/03/23 19:10
S8	6967	("GOI" or (germanium adj on adj insulat\$3) near substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:47
S9	51	("GOI" or (germanium adj on adj insulat\$3) near substrate\$1) same ((dielectric or insulat\$3) near (film\$1 or layer\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 19:13
S10	50	S9 not S5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 19:13
S11	4	S10 and ((wafer\$1 or substrate\$1) near2 bond\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 19:19
S12	46	S10 not S11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 19:19
S13	19	((epitaxial\$2 near ("Ge" or germanium)) near (layer\$1 or film\$1)) same ((dielectric or insulat\$3) near (layer\$1 or film\$1)) same (substrate\$1 or wafer\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:28
S14	0	("2004/0150006").URPN.	USPAT	OR	OFF	2005/03/23 19:46

S15	560	((epitaxial\$2 near ("Ge" or germanium)) near (layer\$1 or film\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 16:52
S16	348	S15 and bond\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 20:09
S17	23	S16 and S2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 20:09
S18	561	((epitaxial\$2 near ("Ge" or germanium)) near (layer\$1 or film\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 16:52
S19	99	((epitaxial\$2 adj ("Ge" or germanium)) adj (layer\$1 or film\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 16:52
S20	0	((((germanium adj on adj insulat\$3) near substrate\$1) same bond\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:48
S21	0	((((germanium adj on adj insulat\$3) near substrate\$1) and bond\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:48
S22	0	((germanium adj on adj insulat\$3) near substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:49

S23	0	((germanium adj on adj insulat\$3) near3 substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:49
S24	0	((germanium adj on adj insulat\$3) same substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:49
S25	0	(germanium adj on adj insulat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:50
S26	6974	(germanium adj on adj insulat\$3) or "GOI"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:51
S27	0	(germanium adj on adj insulat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:51
S28	0	(germanium adj on adj insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:52
S29	0	germanium adj on adj insulat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:52
S30	744	germanium near2 insulat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 16:30

S31	569	S30 same (substrate\$1 or wafer\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:53
S32	337	S31 and bond\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 14:54
S33	10	("5315143" "5461250" "5583059" "5679970" "5917210" "6387739" "6396108" "6548870" "6580129" "6617636").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/28 15:28
S34	4	("5313075" "5627084" "5726459" "5869359").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/28 15:31
S35	0	("6501135").URPN.	USPAT	OR	OFF	2005/03/28 15:32
S36	1	2004-814137.NRAN.	DERWENT	OR	OFF	2005/03/28 15:38
S37	1	2004-814137.NRAN.	DERWENT	OR	OFF	2005/03/28 15:38
S38	4231	((438/149) or (438/311) or (438/455) or (438/479) or (438/933) or (438/964) or (438/967)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/22 16:29
S39	4231	((438/149) or (438/311) or (438/455) or (438/479) or (438/933) or (438/964) or (438/967)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/27 16:08
S40	58	S39 and (((("Ge" or germanium) near2 (layer\$1 or film\$1)) near5 insulat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 16:43
S41	7949	((("Ge" or germanium) near2 (layer\$1 or film\$1)) near5 insulat\$3) or ("GOI" or germanium adj on adj insulat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 16:45

S42	7219	(germanium or Ge) same SOI	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 18:41
S43	112	S42 and goi	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 18:43
S44	1	("6933566").PN.	USPAT	OR	OFF	2005/08/23 18:43